

BDX34/A/B/C

Power Linear and Switching Applications

- High Gain General Purpose
- Power Darlington TR
- Complement to BDX33/33A/33B/33C respectively



1.Base 2.Collector 3.Emitter

PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage		
	: BDX34	- 45	V
	: BDX34A	- 60	V
	: BDX34B	- 80	V
	: BDX34C	- 100	V
V _{CEO}	Collector-Emitter Voltage		
	: BDX34	- 45	V
	: BDX34A	- 60	V
	: BDX34B	- 80	V
	: BDX34C	- 100	V
I _C	Collector Current (DC)	- 10	А
I _{CP}	*Collector Current (Pulse)	- 15	А
I _B	Base Current	- 0.25	А
P _C	Collector Dissipation (T _C =25°C)	70	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 65 ~ 150	°C

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Electrical	Characteristics	T _C =25°C unless otherwise noted
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Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V _{CEO} (sus)	* Collector-Emitter Sustaining Voltage : BDX34 : BDX34A : BDX34B : BDX34C	I _C = -100mA, I _B = 0	- 45 - 60 - 80 - 100			V V V
V _{CER} (sus)	* Collector-Emitter Sustaining Voltage : BDX34 : BDX34A : BDX34B : BDX34C	I _C = -1 00mA, I _B = 0 R _{BE} = 100Ω	- 45 - 60 - 80 - 100			V V V
V _{CEV} (sus)	* Collector-Emitter Sustaining Voltage : BDX34 : BDX34A : BDX34B : BDX34C	I _C = - 100mA, I _B = 0 V _{BE} = - 1.5V	- 45 - 60 - 80 - 100			V V V
I _{CBO}	Collector Cut-off Current : BDX34 : BDX34A : BDX34B : BDX34C	$V_{CB} = -45V, I_{E} = 0$ $V_{CB} = -60V, I_{E} = 0$ $V_{CB} = -80V, I_{E} = 0$ $V_{CB} = -100V, I_{E} = 0$			- 0.2 - 0.2 - 0.2 - 0.2	mA mA mA
I _{CEO}	Collector Cut-off Current : BDX34 : BDX34A : BDX34B : BDX34C	V _{CE} = - 22V, I _B = 0 V _{CE} = - 30V, I _B = 0 V _{CE} = - 40V, I _B = 0 V _{CE} = - 50V, I _B = 0			- 0.5 - 0.5 - 0.5 - 0.5	mA mA mA
I _{EBO} h _{FE}	Emitter Cut-off Current * DC Current Gain : BDX34/34A : BDX34B/34C	$V_{EB} = -5V$, $I_{C} = 0$ $V_{CE} = -3V$, $I_{C} = -4A$ $V_{CE} = -3V$, $I_{C} = -3A$	750 750		- 5	mA
V _{CE} (sat)	* Collector-Emitter Saturation Voltage : BDX34/34A : BDX34B/34C	I _C = - 4A, I _B = - 8mA I _C = - 3A, I _B = - 6mA			- 2.5 - 2.5	V V
V _{BE} (on)	* Base-Emitter ON Voltage : BDX34/34A : BDX34B/34C	V _{CE} = - 3V, I _C = - 4A V _{CE} = - 3V, I _C = - 3A			- 2.5 - 2.5	V V
V _F	* Parallel Diode Forward Voltage	I _F = - 8A			- 4	V

^{*} Pulse Test: PW=300μs, duty Cycle =1.5% Pulsed

Typical Characteristics

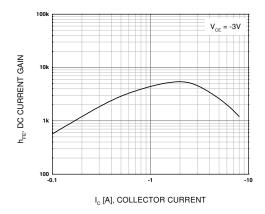


Figure 1. DC Current Gain

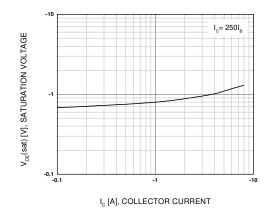


Figure 2. Collector-Emitter Saturation Voltage

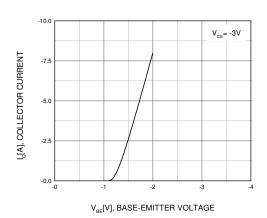


Figure 3. Base-Emitter On Voltage

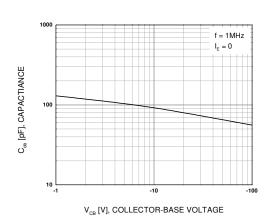


Figure 4. Output Capacitance

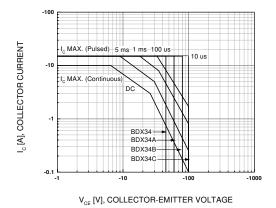


Figure 5. Safe Operating Area

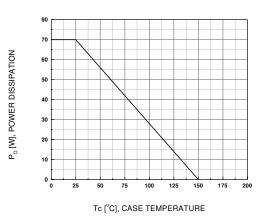
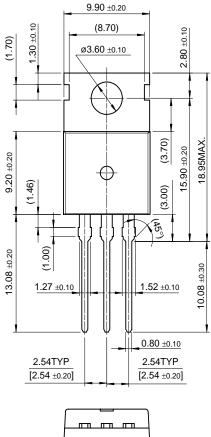


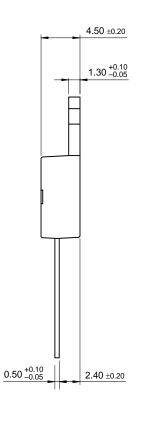
Figure 6. Power Derating

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Package Demensions

TO-220





10.00 ±0.20

Dimensions in Millimeters

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